



## SURFACE MOUNT HIGH VOLTAGE DIODE

### Product Summary (@T<sub>A</sub> = +25°C)

V <sub>R</sub>	I <sub>R</sub>	t <sub>rr</sub>
250V	100nA	50ns

## Description

The BAV21HWF is a 250V, 100nA and 50ns switching diode that is optimized for high reverse breakdown voltage.

# Applications

It is ideally suited for use in applications such as the following:

- Mobile
- Portable Electronics
- Consumer Electronics
- Automotive

### Features

- High Reverse Breakdown Voltage
- Flat Leadframe Design for Improved Thermal Transfer
- High Conductance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

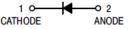
## **Mechanical Data**

- Case: SOD123F
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Bar
- Terminals: Matte Tin Finish Annealed over Copper Alloy Leadframe. Solderable per MIL-STD-202, Method 208 (2)
- Weight: 0.018 grams (Approximate)

### SOD123F







Top View

Bottom View

Ordering Information (Note 4)

Product	Compliance	Case	Packaging
BAV21HWF-7	AEC-Q101	SOD123F	3,000/Tape & Reel

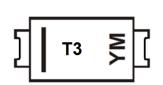
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



SOD123F

T3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex.: C = 2015) M = Month (ex: O = October) Bar Denotes Cathode Side

Date Code Key

Notes:

Year	201	5	2016		2017	20	18	2019		2020	2	2021
Code	С		D		E	F	=	G		Н		I
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	250	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	177	V
Forward Continuous Current		I <sub>FM</sub>	400	mA
Average Rectified Output Current		Ιο	200	mA
Repetitive Peak Forward Current		I <sub>FRM</sub>	625	mA
Non-Repetitive Peak Forward Surge Current	@ t = 1.0µs @ t = 100µs @ t = 10ms	I <sub>FSM</sub>	9.0 3.0 1.7	A

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	375	mW
Thermal Resistance Junction to Ambient Air (Note 5)	Reja	330	°C/W
Thermal Resistance Junction to Solder Point	R <sub>0JSP</sub>	70	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

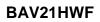
Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V <sub>(BR)R</sub>	250	_	V	I <sub>R</sub> = 100μΑ
Forward Voltage	VF	_	1.0 1.25	V	$I_F = 100 \text{mA}$ $I_F = 200 \text{mA}$
Reverse Current (Note 6)	I <sub>R</sub>	_	100 100	nA μA	V <sub>R</sub> = 200 V, T <sub>J</sub> = +25°C V <sub>R</sub> = 200 V, T <sub>J</sub> = +150°C
Total Capacitance	Ст	_	5.0	pF	V <sub>R</sub> = 0, f = 1.0MHz
Reverse Recovery Time	t <sub>rr</sub>	_	50	ns	$I_F = I_R = 30mA,$ $I_{rr} = 0.1 \times I_R, R_L = 100W$

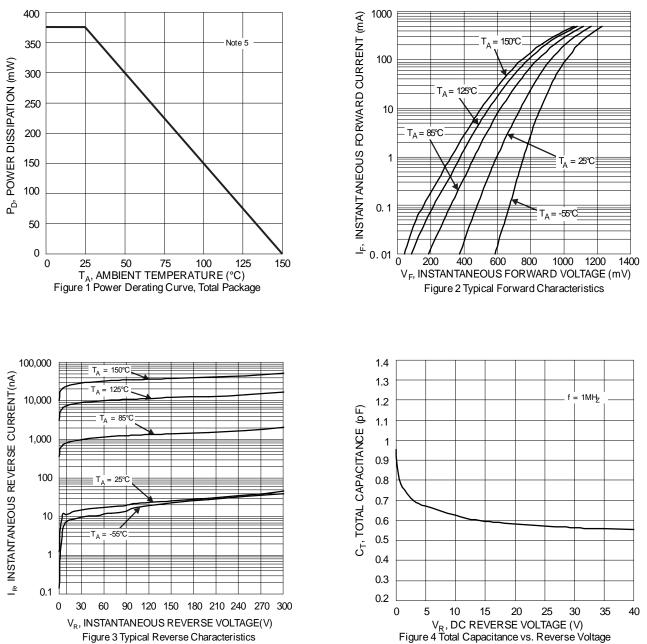
Notes:

5. Part mounted on FR-4 PC board with recommended pad layout, which can be found on our website at http://www.diodes.com.

6. Short duration pulse test used to minimize self-heating effect.





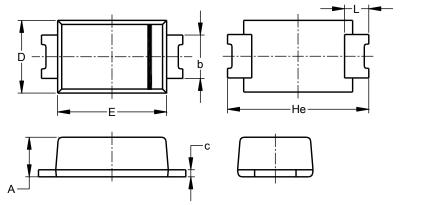




# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

### SOD123F (Type B)

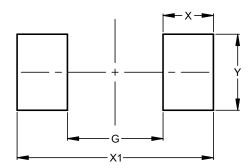


SOD123F (Type B)					
Dim	Min	Max	Тур		
Α	0.81	1.15	_		
b	0.80	1.35	_		
c	0.05	0.30	I		
D	1.70	1.90	1.80		
ш	2.60	2.80	2.70		
He	3.30	3.70	3.50		
L	0.35	0.85	_		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

## SOD123F (Type B)



Dimensions	Value (in mm)
G	1.90
Х	1.00
X1	3.90
Y	1.50



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